

# AB-X3A1XX-X Series SINEWAVE UHF VCXO

Rev. P

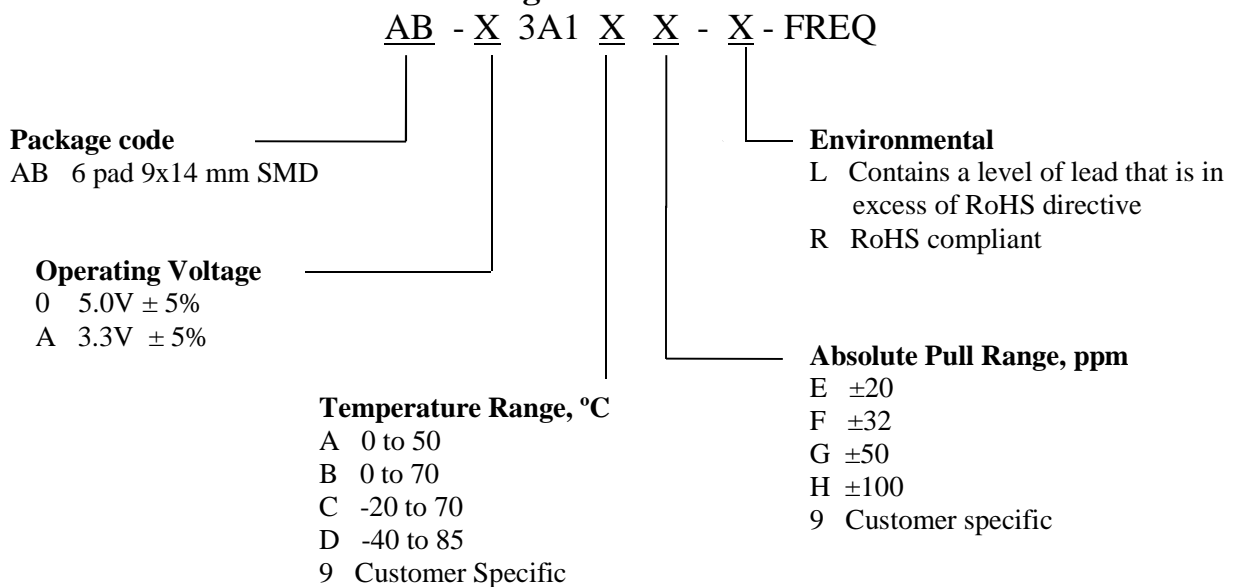
## Description

The **AB-X3A1XX Series** of voltage controlled crystal oscillators (VCXO) provides ultra high frequency with a single-ended sine-wave output. The device is based on low noise analog harmonic frequency multiplication, providing exceptionally low Phase Noise and Jitter. It's packaged in a miniature, FR-4 based 9x14 mm SMD package

## Applications and Features

- Wide frequency range – 200.0MHz to 1.000GHz
- Fiber Channel; 10 GbE; Infiniband; Network Processors; SONET/SDH
- High Reliability – NEL HALT/HASS qualified for crystal oscillator start-up conditions
- Extremely Low Phase Noise and Jitter
- High Shock Resistance, to 1000g
- Absolute Pull Range (APR) to  $\pm 1000$  ppm
- SONET  $\pm 20$  ppm overall free-run stability available
- COTS/Dual use

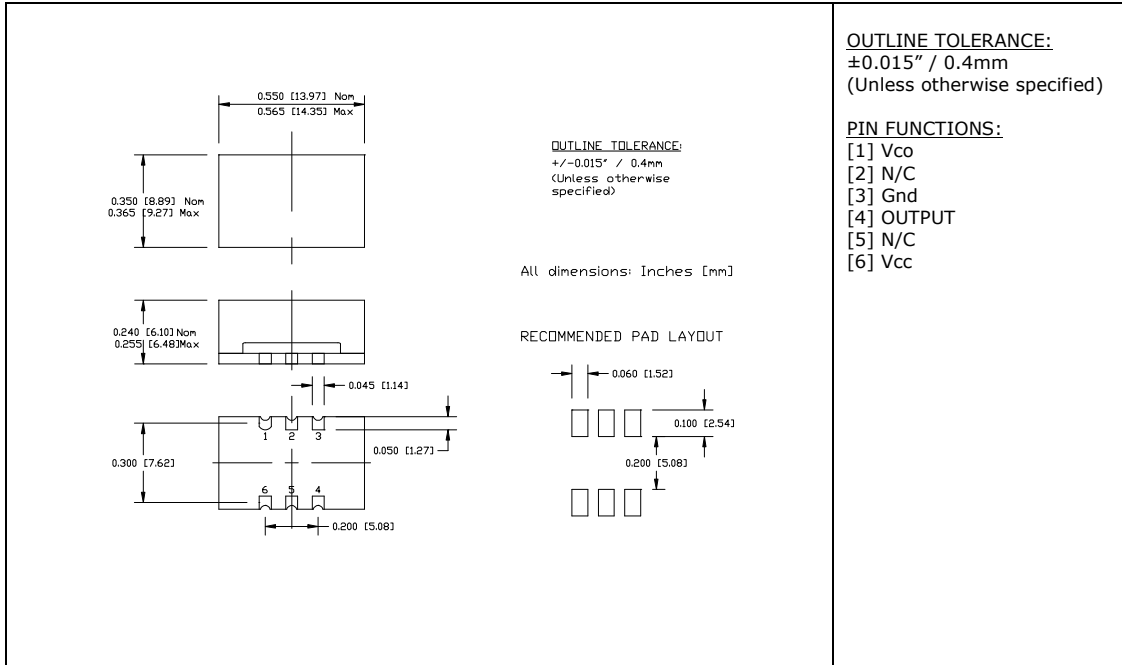
### Creating a Part Number



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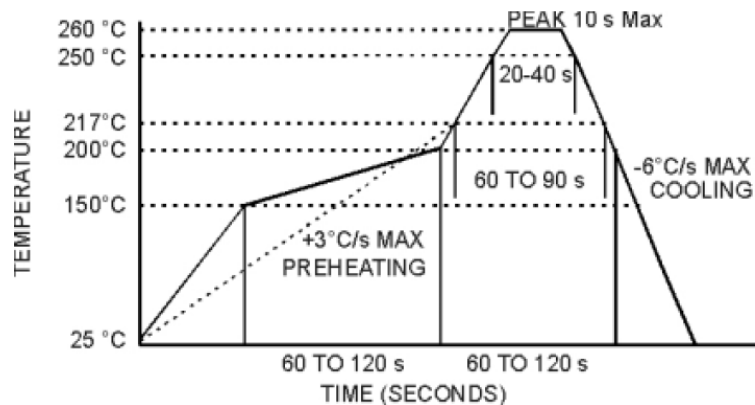
**Drawing Specification**



**Environmental and Mechanical Characteristics**

<b>Operating temp. range</b>	see part # table
<b>Mechanical Shock</b>	Per MIL-STD-202, Method 213, Cond. A
<b>Thermal Shock</b>	Per MIL-STD-883, Method 1011, Cond. A
<b>Vibration</b>	Per MIL-STD-883, Method 2007, Cond. A
<b>Hermetic Seal</b>	Leak rate less than 1x10 <sup>-8</sup> atm.cc/s of helium
<b>Soldering conditions</b>	See MAX reflow profile below; The device may be reflowed once. Reflowing upside down is not allowed. NO CLEAN assembly is recommended

**MAX Reflow Profile**



The device may be reflowed once. Reflowing upside down is not allowed. NO CLEAN assembly is recommended



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**Absolute Maximum Ratings**

Parameter	Symbol	Value	Unit
Operating Temperature Range	To	-40 to +85	°C
Storage Temperature Range	Tst	-50 to +90	°C
Supply Voltage	Vcc	-0.5 to 4.5	V

**Electrical Parameters (1)**

Parameter	Symb	Conditions, Note	MIN	TYP	MAX	Unit	
Nominal Frequency	Fo		200		1000	MHz	
Supply Voltage	Vcc	Code 0 Code A	4.75 3.135	5.0 3.3	5.25 3.465	V	
Supply current	Icc	Vcc=3.3V, 50 ohm load Vcc=5.0V, 50 ohm load		60 80	75 90	mA	
Output Power	Pout	Vcc=3.3V, 50 ohm load </=400MHz Vcc=5.0V, 50 ohm load </=400MHz	0 4	3 7	16	dBm	
Output Power	Pout	Vcc=3.3V, 50 ohm load >400MHz Vcc=5.0V, 50 ohm load >400MHz	-5 0	0 5	5	dBm	
Load		Internally AC coupled	45	50	55	Ohm	
Output Impedance				50		Ohm	
Return Loss				10		dB	
<b>Jitter</b>	Integrated	J	Integrated from Phase Noise, 12 KHz to 20 MHz, RMS		0.1	0.2	ps
			100Hz to 80KHz,RMS			1.0	ps
			50 KHz to 80 MHz		0.3		ps
	Wavecrest characterized		Random period,		2.5		ps
Accumul., pk- to-pk				25		ps	
Deterministic.				1		ps	
Phase Noise	£(Δf)	622.08MHz, APR 50 ppm or less	@ 10 Hz @ 100 Hz @ 1 KHz @ 10KHz @ 100KHz @ >1MHz	-65 -90 -118 -145 -150 -155	-60 -85 -113 -140 -145 -150	dBc/Hz	
Sub-harmonics		@ 622.08MHz		-50	-46	dBc	
Frequency Stability	ΔF/F	Overall, including temperature, aging 10 years, shock and vibration @ Vc=Vcc/2; APR 50ppm, or less	±20	±30		ppm	
Control Voltage Range	Vc		0V		Vcc	V	
Setability	Vcs	Vc to set F at Fo; T, Vcc, load – nominal as shipped	0.4 Vcc	0.5 Vcc	0.6 Vcc	V	
Absolute Pull Range	APR	Overall conditions, see part # creation	20,32, 50,100			ppm	
Input Impedance	Zin	@ Fmod < 100kHz	50			KOhm	
Modulation Bandwidth		At Vc = Vcc/2, -3dB	20			KHz	

Note 1. All parameters, unless otherwise specified, are at nominal conditions, ie: T=25°C, Nominal Vcc & Nominal Load.

